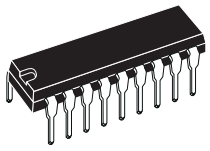
ULQ2801A
ULQ2802A - ULQ2803A
ULQ2804A - ULQ2805A

EIGHT DARLINGTON ARRAYS

- EIGHT DARLINGTONS PER PACKAGE
- **EXTENDED TEMPERATURE RANGE (– 40 to 105°C)**
- OUTPUT CURRENT TO 500mA
- OUTPUT VOLTAGE TO 50V
- INTEGRAL SUPPRESSION DIODES
- VERSIONS FOR ALL POPULAR LOGIC FAMILIES
- OUTPUT CAN BE PARALLELED
- INPUTS PINNED OPPOSITE OUTPUTS TO SIMPLIFY BOARD LAYOUT



DIP18
(Plastic Package)

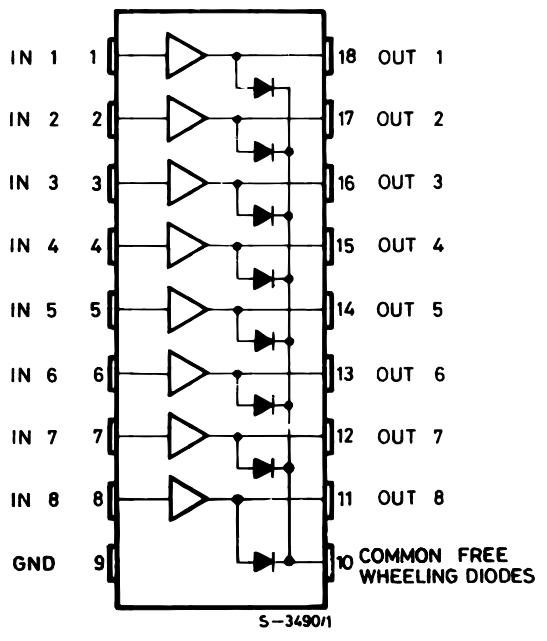
DESCRIPTION

The ULQ2801A-ULQ2805A each contain eight darlington transistors with common emitters and integral suppression diodes for inductive loads. Each darlington features a peak load current rating of 600mA (500mA continuous) and can withstand at least 50V in the off state. Outputs may be paralleled for higher current capability.

Five versions are available to simplify interfacing to standard logic families : the ULQ2801A is designed for general purpose applications with a current limit resistor ; the ULQ2802A has a 10.5kΩ input resistor and zener for 14-25V PMOS ; the ULQ2803A has a 2.7kΩ input resistor for 5V TTL and CMOS ; the ULQ2804A has a 10.5kΩ input resistor for 6-15V CMOS and the ULQ2805A is designed to sink a minimum of 350mA for standard and Schottky TTL where higher output current is required.

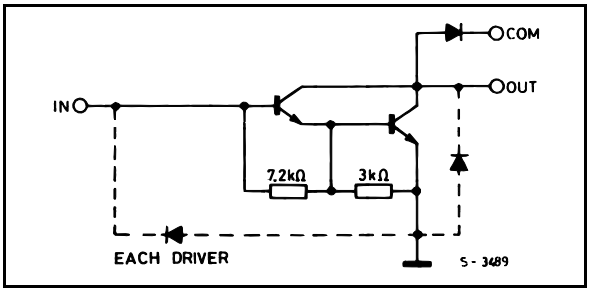
All types are supplied in a 18-lead plastic DIP with a copper lead frame and feature the convenient input-opposite-output pinout to simplify board layout.

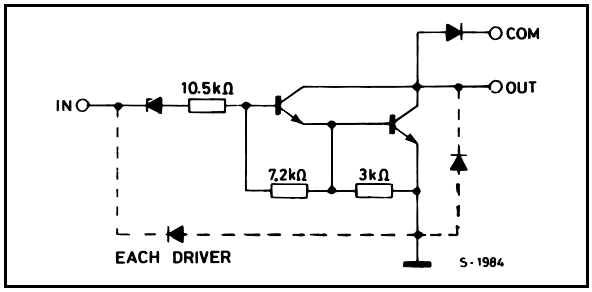
PIN CONNECTION (top view)



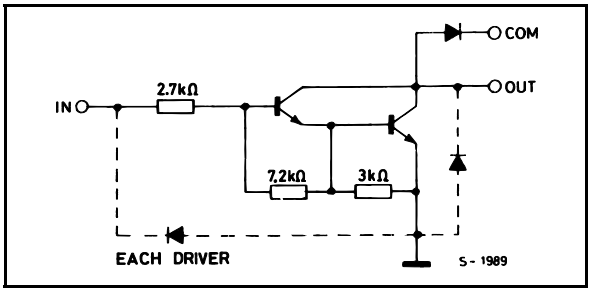
SCHEMATIC DIAGRAM AND ORDER CODES

For ULQ2801A (each driver for PMOS-CMOS) For ULQ2802A (each driver for 14-15 V PMOS)

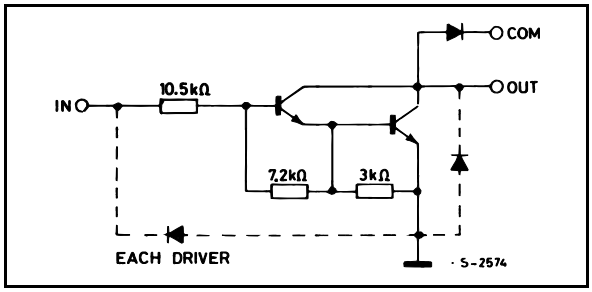




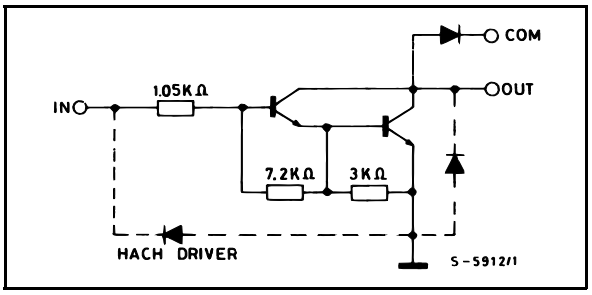
For ULQ2803A (each driver for 5 V, TTL/CMOS)



For ULQ2804A (each driver for 6-15 V CMOS/PMOS



For ULQ2805A (each driver for high out TTL)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_o	Output Voltage	50	V
V_i	Input Voltage for ULQ2802A, 2803A, 2804A for ULQ2805A	30 15	V V
I_C	Continuous Collector Current	500	mA
I_B	Continuous Base Current	25	mA
P_{tot}	Power Dissipation (one Darlington pair) (total package)	1.0 2.25	W W
T_{amb}	Operating Ambient Temperature Range	– 40 to 105	°C
T_{stg}	Storage Temperature Range	– 55 to 150	°C

THERMAL DATA

Symbol	Parameter		Value	Unit
$R_{th\ j\text{-}amb}$	Thermal Resistance Junction-ambient	Max.	55	°C/W

ELECTRICAL CHARACTERISTICS (T_j = –40 to 105°C, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit	Fig.
I_{CEX}	Output Leakage Current	V_{CE} = 50V T_J = 105°C, V_{CE} = 50V T_J = 105°C for **ULQ2802A** V_{CE} = 50V, V_i = 6V for **ULQ2804A** V_{CE} = 50V, V_i = 1V			50 100 500 500	µA µA µA µA	1a 1a 1b 1b
$V_{CE\ (sat)}$	Collector-emitter Saturation Voltage	I_C = 100mA, I_B = 250µA I_C = 200mA, I_B = 350µA I_C = 350mA, I_B = 500µA		0.9 1.1 1.3	1.1 1.3 1.6	V V V	2
$I_{i(on)}$	Input Current	for **ULQ2802A** V_i = 17V for **ULQ2803A** V_i = 3.85V for **ULQ2804A** V_i = 5V V_i = 12V for **ULQ2805A** V_i = 3V		0.82 0.93 0.35 1 1.5	1.25 1.35 0.5 1.45 2.4	mA mA mA mA mA	3
$I_{i(off)}$	Input Current	T_J = 105°C, I_C = 500µA	50	65		µA	4
$V_{i(on)}$	Input Voltage	for **ULQ2802A** V_{CE} = 2V, I_c = 300mA for **ULQ2803A** V_{CE} = 2V, I_c = 200mA V_{CE} = 2V, I_c = 250mA V_{CE} = 2V, I_c = 300mA for **ULQ2804A** V_{CE} = 2V, I_c = 125mA V_{CE} = 2V, I_c = 200mA V_{CE} = 2V, I_c = 275mA V_{CE} = 2V, I_c = 350mA for **ULQ2805A** V_{CE} = 2V, I_c = 350mA			13 2.4 2.7 3 5 6 7 8 2.4	V V V V V V V V V	5
h_{FE}	DC Forward Current Gain	for **ULQ2802A** V_{CE} = 2V, I_c = 350mA	1000			–	2
C_i	Input Capacitance			15	25 (*)	pF	–
t_{PLH}	Turn-on Delay Time	0.5 V_i to 0.5 V_o		0.25	1 (*)	µs	–
t_{PHL}	Turn-off Delay Time	0.5 V_i to 0.5 V_o		0.25	1 (*)	µs	–
I_R	Clamp Diode Leakage Current	V_R = 50V T_J = 105°C, V_R = 50V			50 100	µA µA	6
V_F	Clamp Diode Forward Voltage	I_F = 350mA		1.7	2	V	7

(*) Guaranteed by design

TEST CIRCUITS

Figure 1a.

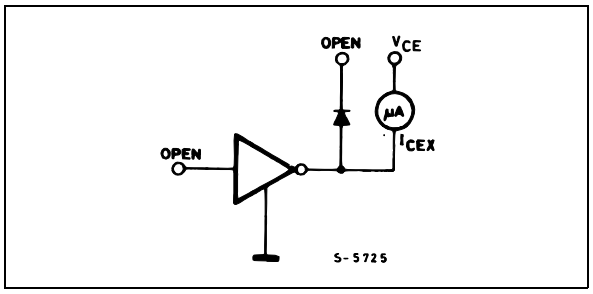


Figure 1b.

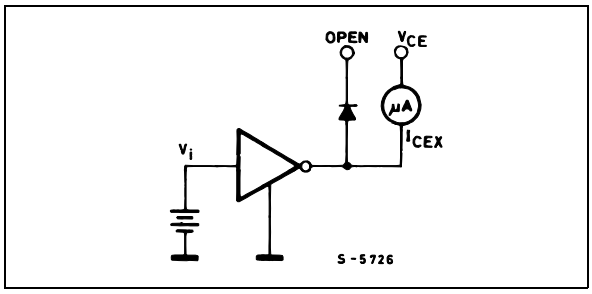


Figure 2.

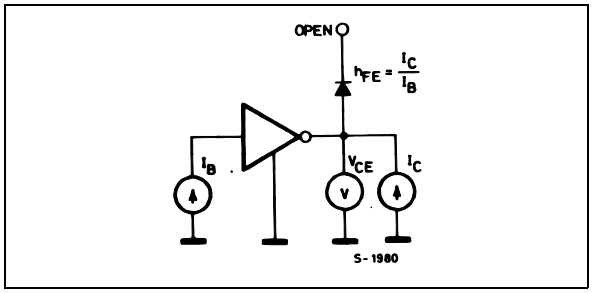


Figure 3.

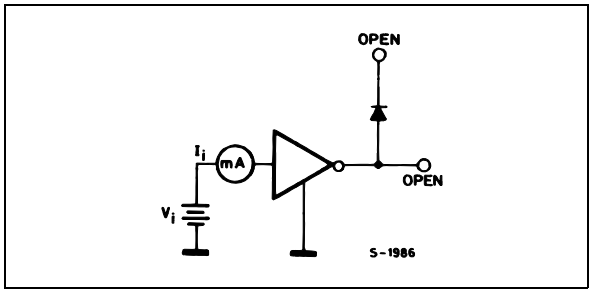


Figure 4.

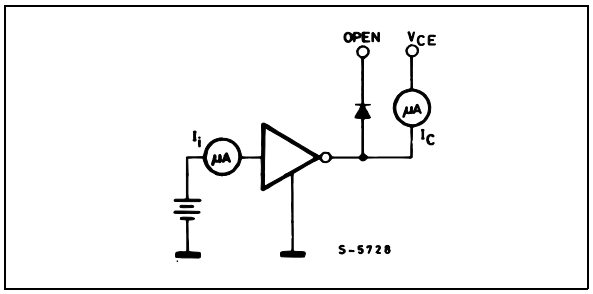


Figure 5.

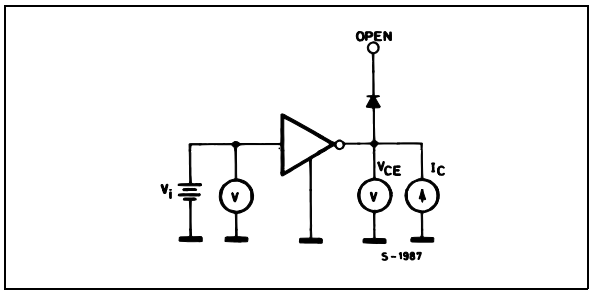


Figure 6.

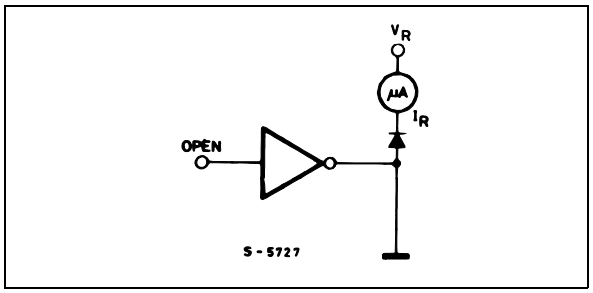


Figure 7.